



## INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

<p>(51) International Patent Classification <sup>6</sup> : G03H 1/02, G06K 19/16, B41M 7/02, 3/14, B42D 15/10</p>	A1	<p>(11) International Publication Number: <b>WO 95/27925</b></p> <p>(43) International Publication Date: 19 October 1995 (19.10.95)</p>
<p>(21) International Application Number: PCT/GB95/00804</p> <p>(22) International Filing Date: 6 April 1995 (06.04.95)</p> <p>(30) Priority Data: 9406794.9                      6 April 1994 (06.04.94)                      GB</p> <p>(71) Applicant (for all designated States except US): APPLIED HOLOGRAPHICS PLC [GB/GB]; 22 Sedling Road, Wear District 6, Washington, Tyne &amp; Wear NE38 9BZ (GB).</p> <p>(72) Inventor; and (75) Inventor/Applicant (for US only): SHEARER, James, Alexander [GB/GB]; Loaningside Farm, Allendale, Hexham, Northumberland NE47 9AN (GB).</p> <p>(74) Agent: GIBSON, Stewart, H.; Urquhart-Dykes &amp; Lord, Three Trinity Court, 21-27 Newport Road, Cardiff CF2 1AA (GB).</p>		<p>(81) Designated States: CA, GB, JP, US, European patent (AT, BE, CH, DE, DK, ES, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE).</p> <p><b>Published</b> <i>With international search report. Before the expiration of the time limit for amending the claims and to be republished in the event of the receipt of amendments.</i></p>
<p>(54) Title: PROTECTED RELIEF PATTERNS</p>		
<p>(57) Abstract</p>		
<p>A surface relief structure comprises a substrate (12) having a surface formed with an optically variable relief pattern, and covered with a protective layer (18). The materials of the protective layer (18) and substrate (12) are soluble in the same solvents, so that the protective layer (18) cannot be dissolved without attacking the surface relief pattern of the substrate (12); the surface relief pattern is therefore protected against copying by taking a mould copy from it.</p>		

**FOR THE PURPOSES OF INFORMATION ONLY**

Codes used to identify States party to the PCT on the front pages of pamphlets publishing international applications under the PCT.

AT	Austria	GB	United Kingdom	MR	Mauritania
AU	Australia	GE	Georgia	MW	Malawi
BB	Barbados	GN	Guinea	NE	Niger
BE	Belgium	GR	Greece	NL	Netherlands
BF	Burkina Faso	HU	Hungary	NO	Norway
BG	Bulgaria	IE	Ireland	NZ	New Zealand
BJ	Benin	IT	Italy	PL	Poland
BR	Brazil	JP	Japan	PT	Portugal
BY	Belarus	KE	Kenya	RO	Romania
CA	Canada	KG	Kyrgystan	RU	Russian Federation
CF	Central African Republic	KP	Democratic People's Republic of Korea	SD	Sudan
CG	Congo	KR	Republic of Korea	SE	Sweden
CH	Switzerland	KZ	Kazakhstan	SI	Slovenia
CI	Côte d'Ivoire	LI	Liechtenstein	SK	Slovakia
CM	Cameroon	LV	Latvia	SN	Senegal
CN	China	LK	Sri Lanka	TD	Chad
CS	Czechoslovakia	LU	Luxembourg	TG	Togo
CZ	Czech Republic	LV	Latvia	TJ	Tajikistan
DE	Germany	MC	Monaco	TT	Trinidad and Tobago
DK	Denmark	MD	Republic of Moldova	UA	Ukraine
ES	Spain	MG	Madagascar	US	United States of America
FI	Finland	ML	Mali	UZ	Uzbekistan
FR	France	MN	Mongolia	VN	Viet Nam
GA	Gabon				

PROTECTED RELIEF PATTERNS

This invention relates to structures having a surface relief pattern, particularly an optically variable relief pattern, for example diffraction gratings and surface relief holograms.

5           Optically variable devices (OVD's), having micro-fringe surface relief patterns (for example embossed or moulded holograms), are increasingly being used as security devices to authenticate documents and other items of value, and to inhibit counterfeiting. There are numerous methods by which masters  
10 for optical variable devices can be originated, and many of these methods have been documented and published: in all instances the surface of the master is formed with a micro-relief pattern of fringes. In order to mass replicate optically variable devices from this original master, the  
15 surface which carries the micro-relief pattern is rendered electrically conductive and a metal coating of nickel, for example, is formed over the surface by electrodeposition from a solution of nickel sulphamate. The nickel deposition, when of a sufficient thickness, is peeled from the surface of the  
20 master and carries a negative of the micro-relief pattern. The nickel member, commonly called a shim, is of robust structure and is then used either to mould or press the micro-relief pattern into blank substrates, to replicate the originally recorded OVD. In the embossing process, the shim is applied  
25 under heat and pressure to the surface of a thermoplastics substrate: this surface is metallised either before or after embossing, providing a degree of reflectivity to enable the e.g. hologram to be viewed under normal light conditions. There are many thermoplastics which will accept such embossing,  
30 including acrylic resins, polyurethane resins, and CAB. In the moulding process, resins mixed with a photoinitiator are used, and are cross-linked after the moulding by exposure to ultraviolet light: metallisation is applied to the micro-relief surface after the moulding, for example by sputtering,  
35 vacuum deposition or electron beam deposition.

When used as security devices, micro-relief OVD'S are

themselves subject to attempts to replicate them as counterfeits. One method which is used is to physically copy the surface relief pattern, by making a mould copy of the genuine OVD. Hitherto, the OVD has been adhered to a document  
5 or other article to be authenticated, by a layer of adhesive (for example a contact adhesive or a hot melt adhesive) applied over the micro-relief surface. However, it is possible by use of certain solvents to remove the adhesive layer without interfering with the underlying relief structure: once the  
10 adhesive layer has been removed and the micro-relief surface is exposed, the relief pattern can be copied.

This invention provides surface relief structures for which the above-described problems are alleviated.

In accordance with this invention, there is provided a  
15 surface relief structure which comprises a substrate having a surface formed with an optically variable relief pattern, and a protective layer covering said surface, in which the material comprising the substrate and the material comprising the protective layer are each independently soluble in the same  
20 solvent, and/or in which the material comprising the protective layer changes physical phase at a temperature not substantially less than that of the material comprising the substrate.

Thus, any chemicals that might be used to remove the protective layer will also attack the underlying substrate in  
25 which the relief pattern is formed, thus destroying the relief pattern. In addition or alternatively, any attempt to melt or evaporate the protective layer will also at least partially melt or evaporate the underlying substrate, again destroying the relief pattern.

30 Generally the resin substrate, in which the surface relief pattern is formed, is soluble in water or in solvents such as MEK, toluene, ethylacetate, isopropylalcohol, etc. The protective layer is preferably of substantially the same resin, or of a resin having similar solubility characteristics as the  
35 substrate resin.

Once the substrate is embossed or moulded, its surface is metallised or coated with a high refractive index layer, before the protective layer is applied. The metallised or high refractive index layer is porous, so that any solvent which is

effective on the protective layer permeates through the substrate and attacks its surface relief pattern. This effect is enhanced if the metallised or high refractive index layer is partially removed, for example in dots, to leave perhaps a  
5 27% cover and a 63% exposure of the substrate.

Typically the substrate, which is formed with the surface relief pattern, comprises a layer applied to a carrier.

Also, in accordance with the invention there is provided a method of producing a surface relief structure,  
10 which comprises providing a substrate with an optically variable relief pattern, and applying a protective covering layer to said relief pattern, the material comprising the substrate and the material comprising the protective layer being each independently soluble in the same solvent and/or the  
15 material comprising the protective layer changes physical phase at a temperature not substantially less than that of the material comprising the relief pattern.

Typically the protective layer is applied in fluid form and is then converted rapidly to a continuous solid layer by  
20 the application of heat, such that the relief pattern remains substantially unchanged.

Embodiments of this invention will now be described by way of examples only and with reference to the accompanying drawings, in which:

25 FIGURE 1 is an enlarged cross-section through a base material prior to embossing;

FIGURE 2 is a similar cross-section through the material after embossing;

30 FIGURE 3 is a similar cross-section through the material after the application of a protective layer over the embossed surface; and

FIGURE 4 is a similar cross-section through a hot stamp foil in accordance with this invention.

Referring to Figure 1, there is shown a material prior  
35 to embossing, comprising a carrier film 10 for example of PET, OPP, PVC etc., having a layer of thermoplastic resin 12 on one surface, which in turn has a thin coating 14 of a material of high refractive index relative to the resin 12: coating 14 may instead be applied after embossing. Figure 2 shows the

material after formation of the micro-relief pattern 16 in its outer surface. Figure 3 shows the material after application of a protective coating 18, of essentially the same resin as the embossed resin layer 12, and an adhesive coating 20 to enable the device to be adhered to a document or other article to be authenticated.

Figure 4 shows an embodiment of foil for hot stamping uses. In this, a release layer 11 is provided between the carrier film 10 and the resin layer 12, so that the carrier film 10 can be removed as the structure is secured, by means of its adhesive coating 20, to the document or other article to be authenticated.

It will be appreciated that in Figures 1 to 4, the resin substrate 12 is transparent: in Figures 1 to 3 the carrier film is also transparent. The coating 14 typically comprises aluminium but may comprise other metals, and is typically applied by sputtering, vacuum deposition or electron beam deposition to a thickness of several molecules only. The coating 14 may comprise a rare earth oxide (e.g. titanium oxide) instead of metal. The coating 14 provides a degree of reflectivity so that the hologram or other image is visible through the carrier film 10 and substrate 12.

Preferably after the coating 14 is applied, it is partially removed by firstly covering discrete areas with a resin and then etching away the exposed areas of the coating 14 e.g. with caustic soda, before then the protective layer 18 is applied.

The protective layer 18 and the substrate 12 are chosen of the same base materials, or of materials soluble in the same solvents. Accordingly, any solvent used to dissolve the protective layer 18 will also attack the substrate 12 and so destroy its relief pattern.

The substrate 12 may comprise a water-based or solvent-based lacquer or coating formulation: after this has been applied to the carrier 10 and cured, the surface relief pattern 16 is formed by embossing (before or after application of the high refractive index coating 14). The protective layer 18 is then applied: this also preferably comprises a water-based or solvent-based lacquer or coating formulation which is then

subjected to high temperatures to dry it or drive off the solvents, before these have time to attack the substrate 12.

The surface relief pattern 16 may be any form of optically variable relief pattern, i.e. providing a different  
5 image or appearance when viewed (through the substrate) from different angles. For example the relief pattern may comprise a micro-fringe relief pattern or an interference relief pattern (particularly a diffraction grating pattern such as a hologram).

CLAIMS

- 1) A surface relief structure which comprises a substrate having a surface formed with an optically variable relief pattern, and a protective layer covering said surface, in which  
5 the material comprising the substrate and the material comprising the protective layer are each independently soluble in the same solvent, and/or in which the material comprising the protective layer changes physical phase at a temperature not substantially less than that of the material comprising the  
10 substrate.
- 2) A surface relief structure according to claim 1, wherein the protective layer comprises an aqueous based coating formulation.
- 3) A surface relief structure according to claim 1,  
15 wherein the protective layer comprises a solvent based coating formulation.
- 4) A surface relief structure according to claim 2 or 3, wherein said coating formulation comprises a base polymer, and the material comprising the substrate comprises substantially  
20 the same base polymer.
- 5) A surface relief structure according to any of claims 1 to 4, wherein the substrate is in the form of a coating applied to a carrier.
- 6) A surface relief structure according to claim 5,  
25 wherein said carrier comprises a film or sheet of plastics.
- 7) A surface relief structure according to any of claims 1 to 6, which includes an intermediate layer interposed between said relief pattern and said protective layer, said intermediate layer having a higher refractive index than that  
30 of the substrate.



- 8) A surface relief structure according to claim 7, wherein the intermediate layer comprises a metal.
- 9) A surface relief structure according to claim 7 or 8, wherein said intermediate layer is porous.
- 5 10) A surface relief structure according to claim 9, wherein said intermediate layer is foraminous.
- 11) A surface relief structure as claimed in any preceding claim, in which said substrate is transparent.
- 12) A surface relief structure as claimed in any preceding  
10 claim, further comprising an adhesive coating applied to said protective layer.
- 13) A surface relief structure as claimed in any preceding claim, in which said relief pattern comprises a micro-fringe relief pattern.
- 15 14) A surface relief structure as claimed in any one of claims 1 to 13, in which said relief pattern comprises an optical interference relief pattern.
- 15) A surface relief structure as claimed in claim 14, in which said relief pattern comprises a diffraction grating  
20 pattern.
- 16) A surface relief structure as claimed in claim 15, in which said relief pattern comprises a hologram.
- 17) A method of producing a surface relief structure, which  
25 comprises providing a substrate with an optically variable relief pattern, and applying a protective covering layer to said relief pattern, the material comprising the substrate and the material comprising the protective layer being each independently soluble in the same solvent and/or the material comprising the protective layer changes physical phase at a

temperature not substantially less than that of the material comprising the relief pattern.

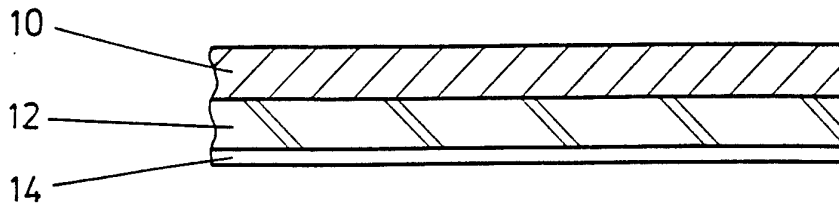


FIG. 1

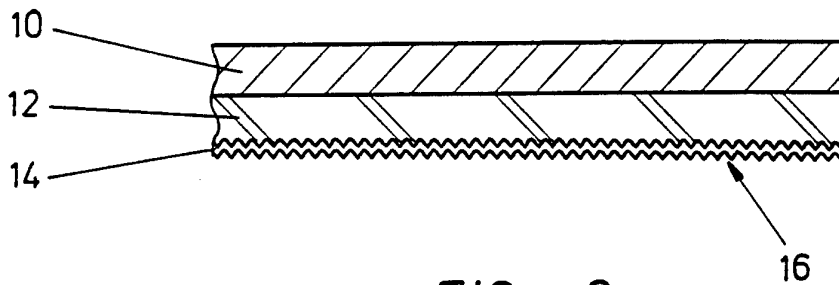


FIG. 2

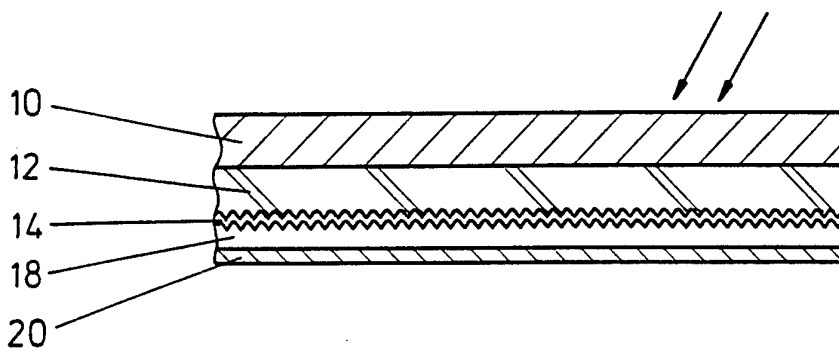


FIG. 3

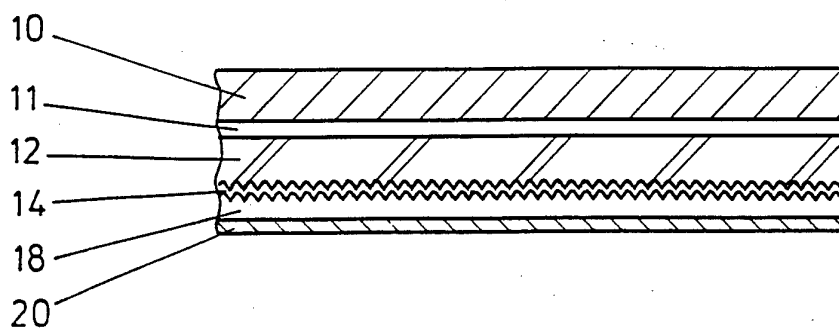


FIG. 4

**INTERNATIONAL SEARCH REPORT**

International Application No  
PCT/GB 95/00804

A. CLASSIFICATION OF SUBJECT MATTER  
IPC 6 G03H1/02 G06K19/16 B41M7/02 B41M3/14 B42D15/10

According to International Patent Classification (IPC) or to both national classification and IPC

**B. FIELDS SEARCHED**

Minimum documentation searched (classification system followed by classification symbols)  
IPC 6 G03H B42D G06K B41M

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

**C. DOCUMENTS CONSIDERED TO BE RELEVANT**

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	GB,A,1 165 556 (IBM) 1 October 1969 see page 2, line 99 - line 106 see page 3, line 3 - line 12; claim 5 ---	1-17
X	US,A,4 119 361 (D.L. LESLIE) 10 October 1978 see column 4, line 18 - line 22; claims see column 3, line 5 - line 8 ---	1-17
X	GB,A,2 093 404 (RCA CORP) 2 September 1982 see column 4, line 121 - line 130 ---	1-17
X	EP,A,0 145 481 (E-I. DU PONT DE NEMOURS AND COMPANY) 19 June 1985 see page 4, line 14 - line 25 ---	1-17
	-/--	

Further documents are listed in the continuation of box C.

Patent family members are listed in annex.

\* Special categories of cited documents :

- \*A\* document defining the general state of the art which is not considered to be of particular relevance
- \*E\* earlier document but published on or after the international filing date
- \*L\* document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)
- \*O\* document referring to an oral disclosure, use, exhibition or other means
- \*P\* document published prior to the international filing date but later than the priority date claimed

\*T\* later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention

\*X\* document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone

\*Y\* document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art.

\*&\* document member of the same patent family

Date of the actual completion of the international search

9 August 1995

Date of mailing of the international search report

17. 08. 95

Name and mailing address of the ISA

European Patent Office, P.B. 5818 Patentlaan 2  
NL - 2280 HV Rijswijk  
Tel. (+ 31-70) 340-2040, Tx. 31 651 epo nl,  
Fax (+ 31-70) 340-3016

Authorized officer

Rasschaert, A

## INTERNATIONAL SEARCH REPORT

International Application No  
PCT/GB 95/00804

## C.(Continuation) DOCUMENTS CONSIDERED TO BE RELEVANT

Category	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	GB,A,2 219 248 (DAVID JULIAN PIZZANELL) 6 December 1989 see claims; figures ---	1
A	EP,A,0 251 253 (FABBIANI BRUNO) 7 January 1988 see the whole document ---	1
A	US,A,3 703 407 (W.J. HANNAN ET AL.) 21 November 1972 see the whole document ---	1
A	EP,A,0 466 118 (GAO ) 15 January 1992 see the whole document -----	1

## INTERNATIONAL SEARCH REPORT

 International Application No  
 PCT/GB 95/00804

Patent document cited in search report	Publication date	Patent family member(s)	Publication date
GB-A-1165556	01-10-69	DE-A- 1646242	08-07-71
		FR-A- 1519954	05-08-68
US-A-4119361	10-10-78	CH-A- 588358	31-05-77
		BE-A- 845175	01-12-76
		CA-A- 1060917	21-08-79
		DE-A- 2538956	17-02-77
		FR-A, B 2321158	11-03-77
		GB-A- 1519715	02-08-78
		JP-A- 52024000	23-02-77
		SE-B- 418229	11-05-81
		SE-A- 7608967	15-02-77
GB-A-2093404	02-09-82	US-A- 4892385	09-01-90
		CA-A- 1185370	09-04-85
		CH-A- 661602	31-07-87
		DE-A- 3206062	19-08-82
		FR-A, B 2500020	20-08-82
		JP-C- 1373457	07-04-87
		JP-A- 57159696	01-10-82
		JP-B- 60023040	05-06-85
		NL-A- 8200656	16-09-82
		EP-A-145481	19-06-85
JP-A- 60191284	28-09-85		
GB-A-2219248	06-12-89	NONE	
EP-A-251253	07-01-88	CA-A- 1297517	17-03-92
		DE-A- 3782863	14-01-93
		JP-A- 63092497	22-04-88
		US-A- 4889366	26-12-89
US-A-3703407	21-11-72	NONE	
EP-A-466118	15-01-92	DE-A- 4021908	16-01-92
		AU-B- 642030	07-10-93
		AU-A- 8028891	16-01-92
		CA-A- 2046711	11-01-92
		JP-A- 4331972	19-11-92